## SQJ138ELP

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**Vishay Siliconix** 

## Automotive N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY	
V <sub>DS</sub> (V)	40
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0015
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.0022
I <sub>D</sub> (A)	315
Configuration	Single
Package	PowerPAK SO-8L

#### FEATURES

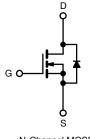
- TrenchFET<sup>®</sup> Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R<sub>q</sub> and UIS tested
- Q<sub>gd</sub>/Q<sub>gs</sub> ratio < 1 optimizes switching characteristics</li>



COMPLIANT HALOGEN

FREE

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



N-Channel MOSFET

ABSOLUTE MAXIMUM RATING	<b>iS</b> (T <sub>C</sub> = 25 °C, unles	s otherwise noted	i)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V <sub>DS</sub>	40	v
Gate-source voltage		V <sub>GS</sub>	± 20	V
Continuous drain current	T <sub>C</sub> = 25 °C	1	315	
	T <sub>C</sub> = 125 °C	۱ <sub>D</sub>	182	
Continuous source current (diode conduction)		I <sub>S</sub>	296	А
Pulsed drain current <sup>a</sup>		I <sub>DM</sub>	534	
Single pulse avalanche current	ulse avalanche current L = 0.1 mH		39.5	
Single pulse avalanche energy	L = 0.1 mm	E <sub>AS</sub>	78	mJ
laximum power dissipation <sup>a</sup>	T <sub>C</sub> = 25 °C	PD	500	w
Maximum power dissipation ~	T <sub>C</sub> = 125 °C	FD	166	vv
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C
Soldering recommendations (peak temperature) <sup>c</sup>			260	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount <sup>b</sup>	R <sub>thJA</sub>	44	°C/W	
Junction-to-case (drain)		R <sub>thJC</sub>	0.46	0/W	

#### Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %

b. When mounted on 1" square PCB (FR4 material)

c. See solder profile (<u>www.vishay.com/doc?73257</u>). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		•						
Drain-source breakdown voltage	V <sub>DS</sub>	$V_{GS} = 0, I_D = 250 \ \mu A$		40	-	-	v	
Gate-source threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$		1.2	1.7	2.2	v	
Gate-source leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	= 0 V, V <sub>GS</sub> = ± 20 V	-	-	± 100	nA	
		$V_{GS} = 0 V$	V <sub>DS</sub> = 40 V	-	-	1		
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 40 V, T <sub>J</sub> = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V <sub>DS</sub> = 40 V, T <sub>J</sub> = 175 °C	-	-	250		
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	30	-	-	Α	
		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 15 A	-	0.0012	0.0015		
Drain actures on state resistance a	Б	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 15 A, T <sub>J</sub> = 125 °C	-	-	0.0022		
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 V$	I <sub>D</sub> = 15 A, T <sub>J</sub> = 175 °C	-	-	0.0027	Ω	
		$V_{GS} = 4.5 V$	I <sub>D</sub> = 15 A	-	0.00173	0.0022		
Forward transconductance b	g <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 10 A		-	85	-	S	
Dynamic <sup>b</sup>		•			•			
Input capacitance	C <sub>iss</sub>		V <sub>DS</sub> = 25 V, f = 1 MHz	-	4775	6685	pF	
Output capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$		-	1467	2054		
Reverse transfer capacitance	C <sub>rss</sub>	1 F		-	128	180	1	
Total gate charge <sup>c</sup>	Qg			-	78	117		
Gate-source charge c	Q <sub>gs</sub>	V <sub>GS</sub> = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 30 \text{ A}$	-	15	-	nC	
Gate-drain charge <sup>c</sup>	Q <sub>gd</sub>			-	14	-		
Gate resistance	R <sub>g</sub>		f = 1 MHz	0.7	1.4	2.1	Ω	
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>			-	14	21	1	
Rise time <sup>c</sup>	tr	$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = 20 \text{ V}, \ R_{\text{L}} = 0.5 \ \Omega \\ I_{\text{D}} \cong 40 \text{ A}, \ V_{\text{GEN}} = 10 \text{ V}, \ R_{\text{g}} = 1 \ \Omega \end{array}$		-	6	9	- ns	
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>			-	38	57		
Fall time <sup>c</sup>	t <sub>f</sub>			-	9	14		
Source-Drain Diode Ratings and Cha	aracteristics <sup>b</sup>				•			
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	1180	Α	
Forward voltage	V <sub>SD</sub>	I <sub>F</sub> = 15 A, V <sub>GS</sub> = 0 V		-	-	1.1	V	
Body diode reverse recovery time	t <sub>rr</sub>	- I <sub>F</sub> = 10 A, di/dt = 100 A/μs		-	48	96	ns	
Body diode reverse recovery charge	Q <sub>rr</sub>			-	50	100	nC	
Reverse recovery fall time	ta			-	24	-		
Reverse recovery rise time	t <sub>b</sub>			-	24	-	ns	
Body diode peak reverse recovery current	I <sub>RM(REC)</sub>			-	1.8	-	А	

Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %

b. Guaranteed by design, not subject to production testing

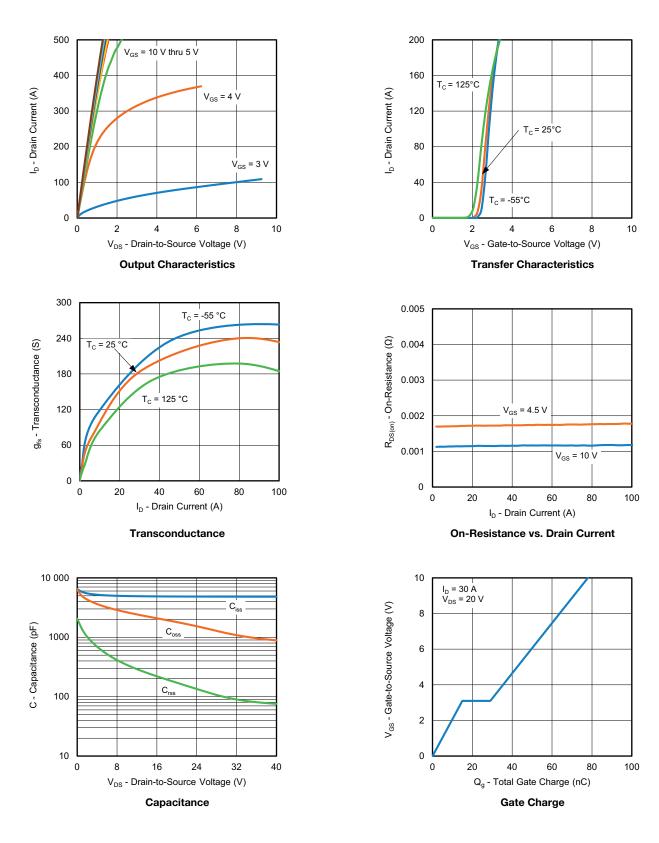
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2



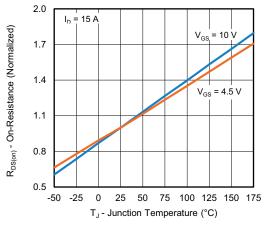
### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



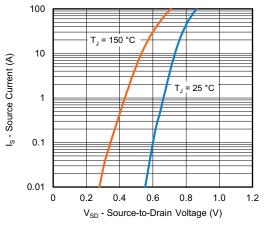
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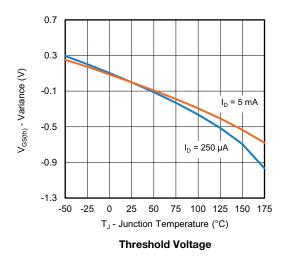
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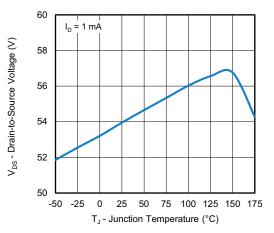


**On-Resistance vs. Junction Temperature** 

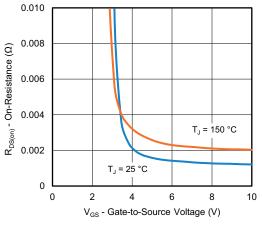


Source Drain Diode Forward Voltage

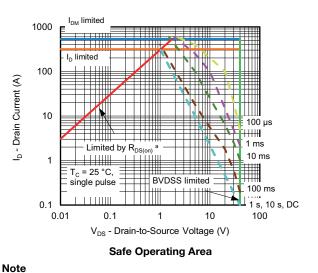




Drain Source Breakdown vs. Junction Temperature



On-Resistance vs. Gate-to Source Voltage



a.  $V_{GS}$  > minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

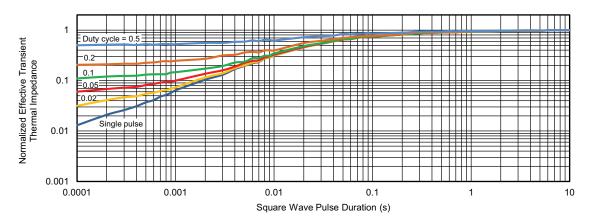
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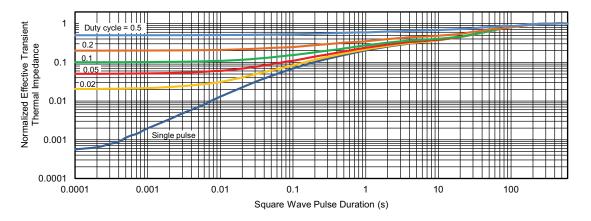
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#### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

#### Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

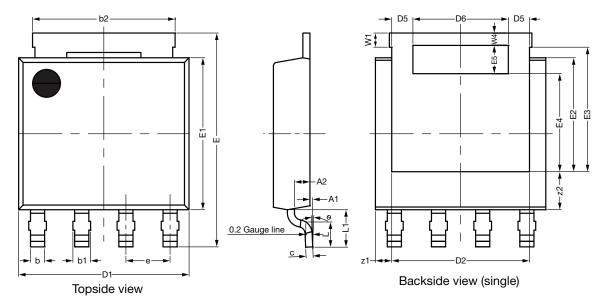
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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# PowerPAK<sup>®</sup> SO-8L Case Outline 3



DIM.		MILLIMETERS		INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.00	1.05	1.10	0.039	0.041	0.043	
A1	0.00		0.127	0.000		0.005	
A2	0.40	0.45	0.50	0.016	0.018	0.020	
b	0.33	0.41	0.49	0.013	0.016	0.019	
b1	0.43	0.51	0.59	0.017	0.020	0.023	
b2	4.00	4.10	4.20	0.157	0.161	0.165	
С	0.15	0.20	0.25	0.006	0.008	0.010	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D5	0.51	0.61	0.71	0.020	0.024	0.028	
D6	2.64	2.74	2.84	0.104	0.108	0.112	
е		1.27 BSC		0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	3.18	3.28	3.38	0.125	0.129	0.133	
E3	3.48	3.58	3.68	0.137	0.141	0.145	
E4	2.72	2.82	2.92	0.107	0.111	0.115	
E5	0.71	0.81	0.91	0.028	0.032	0.036	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
W1	0.31	0.41	0.51	0.012	0.016	0.020	
W4	0.31	0.36	0.41	0.012	0.014	0.016	
z1	0.37	0.47	0.57	0.015	0.019	0.022	
z2	0.99	1.09	1.19	0.039	0.043	0.047	
θ	0°		5°	0°		5°	

Note

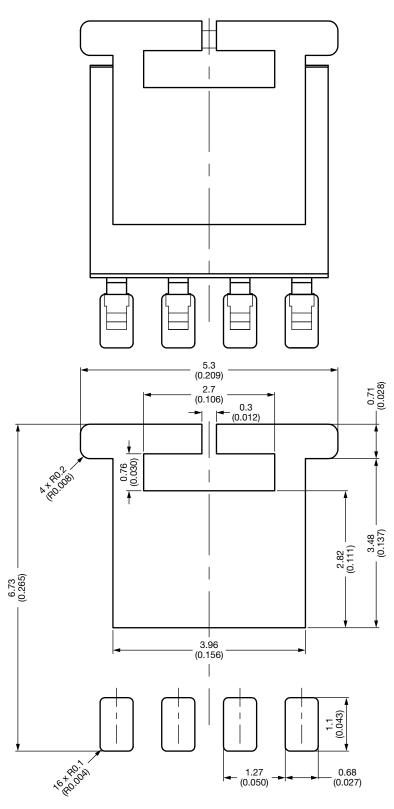
• Millimeter will govern

Revison: 05-Aug-2019

Document Number: 76666



# **Recommended Land Pattern PowerPAK® SO-8L Single Short Ear**



Dimensions in Millimeters (Inches)

Revision: 24-Aug-2021

Document Number: 78020



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